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ON Semiconductor®

RHRP3060 30 A, 600 V Hyperfast Diodes

Features

- Hyperfast Recovery trr = 45 ns (@ IF = 30 A)
- Max Forward Voltage, V_F = 2.1 V (@ T_c = 25°C)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

Applications

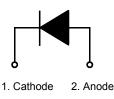
- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Ordering Informations

Part Number	Package	Brand	
RHRP3060	TO-220AC-2L	RHRP3060	

Pin Assignments





The RHRP3060 is a hyperfast diode with soft recovery characteristics. It has the half recovery time of ultrafast

diodes and is silicon nitride passivated ionimplanted

variety of switching power supplies and other power

switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise

epitaxial planar construction. These devices are intended to be used as freewheeling clamping diodes and diodes in a

in many power switching circuits reducing power loss in the

Description

switching transistors.

Absolute Maximum Ratings

Symbol	Parameter	RHRP3060	Unit
V _{RRM}	Peak Repetitive Reverse Voltage	600	V
V _{RWM}	Working Peak Reverse Voltage	600	V
V _R	DC Blocking Voltage	600	V
I _{F(AV)}	Average Rectified Forward Current (T _C = 120°C)	30	А
I _{FRM}	Repetitive Peak Surge Current (Square Wave, 20KHz)	70	А
I _{FSM}	Nonrepetitive Peak Surge Current (Halfwave, 1 Phase, 60Hz)	325	A
P _D	Maximum Power Dissipation	125	W
E _{AVL}	Avalanche Energy (See Figures 10 and 11)	20	mJ
T _J , T _{STG}	Operating and Storage Temperature	-65 to 175	°C

Publication Order Number: RHRP3060/D

Electrical Characteristics T_c = 25°C unless otherwise noted

Symbol	Test Conditions	RHRP3060			11
		Min.	Тур.	Max.	Unit
V _F	I _F = 30 A	-	-	2.1	V
	I _F = 30 A, T _C = 150°C	-	-	1.7	V
I _R	V _R = 400 V	-	-	-	μΑ
	V _R = 600 V	-	-	250	μΑ
	V _R = 400 V, T _C = 150°C	-	-	-	mA
	V _R = 600 V, T _C = 150°C	-	-	1.0	mA
t _{rr}	$I_F = 1 \text{ A}, dI_F/dt = 200 \text{ A}/\mu \text{s}$	-	-	40	ns
	I _F = 30 A, dI _F /dt = 200 A/μs	-	-	45	ns
t _a	I _F = 30 A, dI _F /dt = 200 A/μs	-	22	-	ns
t _b	I _F = 30 A, dI _F /dt = 200 A/μs	-	18	-	ns
Q _{RR}	I _F = 30 A, dI _F /dt = 200 A/μs	-	100	-	nC
CJ	V _R = 600 V, I _F = 0 A	-	85	-	pF
$R_{\theta JC}$		-	-	1.2	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%)

 I_R = Instantaneous reverse current.

 $t_{\rm rr}$ = Reverse recovery time (See Figure 9), summation of $t_{\rm a}$ + $t_{\rm b}.$

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

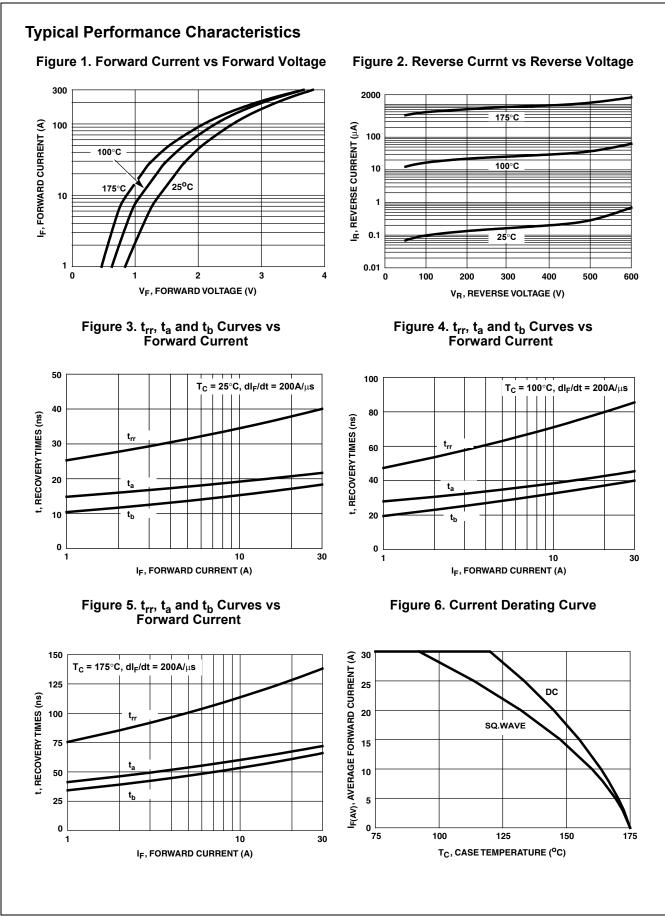
 Q_{RR} = Reverse recovery charge.

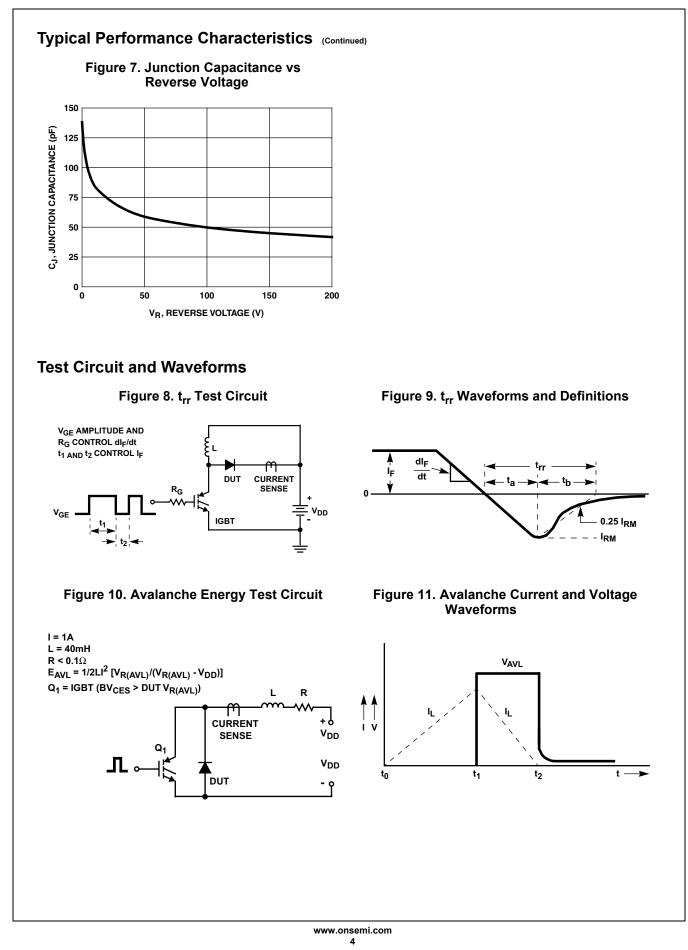
C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = Duty cycle.





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